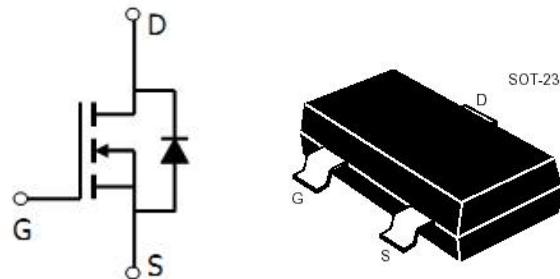


GM2306S

SOT-23 場效應晶體管(SOT-23 Field Effect Transistors)



### N-Channel Enhancement-Mode MOS FETs

N 溝道增強型 MOS 場效應管

#### ■MAXIMUM RATINGS 最大額定值

Characteristic 特性參數	Symbol 符號	Rat 額定值	Unit 單位
Drain-Source Voltage 漏極-源極電壓	$BV_{DSS}$	30	V
Gate- Source Voltage 柵極-源極電壓	$V_{GS}$	$\pm 20$	V
Drain Current (continuous) 漏極電流-連續	$I_D$	3.5	A
Drain Current (pulsed) 漏極電流-脉冲	$I_{DM}$	16	A
Total Device Dissipation 總耗散功率 $T_A=25^\circ\text{C}$ 環境溫度為 $25^\circ\text{C}$	$P_D$	1250	mW
Junction 結溫	$T_J$	150	$^\circ\text{C}$
Storage Temperature 儲存溫度	$T_{stg}$	-55 to +150	$^\circ\text{C}$

GM2306S

### ■ELECTRICAL CHARACTERISTICS 電特性

( $T_A=25^\circ\text{C}$  unless otherwise noted 如無特殊說明，溫度為  $25^\circ\text{C}$ )

Characteristic 特性參數	Symbol 符號	Min 最小值	Typ 典型值	Max 最大值	Unit 單位
Drain-Source Breakdown Voltage 漏極-源極擊穿電壓( $I_D=250\mu\text{A}$ , $V_{GS}=0\text{V}$ )	$\text{BV}_{DSS}$	30	—	—	V
Gate Threshold Voltage 柵極開启電壓( $I_D=250\mu\text{A}$ , $V_{GS}=V_{DS}$ )	$V_{GS(\text{th})}$	1	—	1.8	V
Diode Forward Voltage Drop 內附二極管正向壓降( $I_S=1.25\text{A}$ , $V_{GS}=0\text{V}$ )	$V_{SD}$	—	—	1.2	V
Zero Gate Voltage Drain Current 零柵壓漏極電流( $V_{GS}=0\text{V}$ , $V_{DS}=25\text{V}$ ) ( $V_{GS}=0\text{V}$ , $V_{DS}=25\text{V}$ , $T_A=55^\circ\text{C}$ )	$I_{DSS}$	—	—	1 10	$\mu\text{A}$
Gate Body Leakage 柵極漏電流( $V_{GS}=\pm20\text{V}$ , $V_{DS}=0\text{V}$ )	$I_{GSS}$	—	—	$\pm100$	nA
Static Drain-Source On-State Resistance 静态漏源導通電阻( $I_D=3.5\text{A}$ , $V_{GS}=10\text{V}$ )	$R_{DS(\text{ON})}$	—	53	57	$\text{m}\Omega$
Static Drain-Source On-State Resistance 静态漏源導通電阻( $I_D=2.8\text{A}$ , $V_{GS}=4.5\text{V}$ )	$R_{DS(\text{ON})}$	—	88	94	$\text{m}\Omega$
Input Capacitance 輸入電容 ( $V_{GS}=0\text{V}$ , $V_{DS}=15\text{V}$ , $f=1\text{MHz}$ )	$C_{ISS}$	—	555	—	pF
Output Capacitance 輸出電容 ( $V_{GS}=0\text{V}$ , $V_{DS}=15\text{V}$ , $f=1\text{MHz}$ )	$C_{OSS}$	—	120	—	pF
Turn-ON Time 开启時間 ( $V_{DS}=15\text{V}$ , $I_D=1\text{A}$ , $R_{GEN}=6\Omega$ )	$t_{(\text{on})}$	—	9	—	ns
Turn-OFF Time 短斷時間 ( $V_{DS}=15\text{V}$ , $I_D=1\text{A}$ , $R_{GEN}=6\Omega$ )	$t_{(\text{off})}$	—	17	—	ns

Pulse Width  $\leq 300 \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$